

isc N-Channel MOSFET Transistor

IXFA24N65X2

• FEATURES

- · Drain Source Voltage-
- : V_{DSS}= 650V(Min)
- · Static Drain-Source On-Resistance
- : $R_{DS(on)} \le 100 \text{m} \Omega @V_{GS} = 10 \text{V}$
- Fast Switching
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



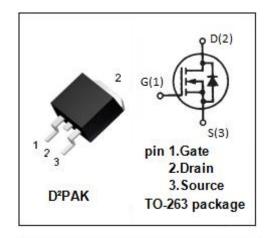
- · Easy to Mount
- · Space Savings
- High Power Density

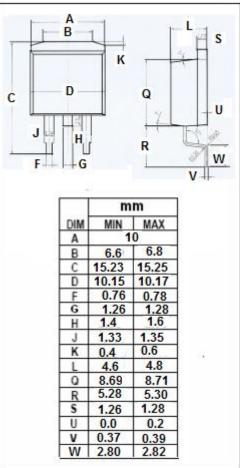
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|---|-------|------------|
| V _{DSS} | Drain-Source Voltage 650 | | V |
| V _{GS} | Gate-Source Voltage-Continuous ±30 | | V |
| I _D | Drain Current-Continuous 34 | | А |
| I _{DM} | Drain Current-Single Plused 68 | | А |
| P _D | Total Dissipation @T _C =25°C 540 | | W |
| Tj | Max. Operating Junction Temperature -55~150 | | $^{\circ}$ |
| T _{stg} | Storage Temperature -55~150 | | $^{\circ}$ |

• THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|---------------------|--------------------------------------|------|------|
| R _{th j-c} | Thermal Resistance, Junction to Case | 0.23 | °C/W |







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• ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

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|----------------------------------|---------------------------------|--|-----|------|------------|------|--|--|
| SYMBOL | PARAMETER | CONDITIONS | MIN | TYPE | MAX | UNIT | | |
| V _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} = 0; I _D = 1mA | 650 | | | V | | |
| $V_{\text{GS(th)}}$ | Gate Threshold Voltage | V _{DS} = V _{GS} ; I _D = 2.5mA | 3.5 | | 5 | V | | |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} = 10V; I _D = 17A | | | 100 | mΩ | | |
| I _{GSS} | Gate-Body Leakage Current | V _{GS} = ±30V;V _{DS} = 0 | | | ±100 | nA | | |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} = 650V; V _{GS} = 0 V _{DS} = 650V; V _{GS} = 0;T _J =125°C | | | 10 1750 | μΑ | | |
| V _{SD} | Diode Forward On-voltage | I _F = 34A ;V _{GS} = 0 | | | 1.4 | V | | |

NOTICE:

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